DECLARATION FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address an		ed below next to my name. e name is listed below) or an original, first and	ioint inv	entor (if
nlural names are listed below) of the	subject matter which is	claimed and for which a patent is sought on the ON BEAM EXPOSURE METHOD, METHOD	e inventi	on
SEMICONDUCTOR DEVI		BEAM EXPOSURE APPARATUS		
the specification of which (check one) [X] is att	ached hereto			
(Check the) [A] is at			as	
			-	_
and w	as amended on		_ (if appl	icable).
amended by an amendment referred	to above.	nts of the above identified specification, includ		
		erial to the examination of this application in a	ccordanc	e with
Title 37, Code of Federal Regulation		ed States Code, §119 of any foreign application	(s) for no	itent or
		elow any foreign application for patent or inver		
having a filing date before that of th				
Prior Foreign Application(s) 11-232358	Tonon	19/08/1999		Claimed
(Number)	Japan (Country)	(Day/Month/Year Filed)	(Yes)	No
(Number)	(Country)	(Day/Month Fear Fried)		
			Yes	No
(Number)	(Country)	(Day/Month/Year Filed)		
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		(D. 04 - 4 0/ 121-1)	Yes	No
(Number)	(Country)	(Day/Month/Year Filed)		
(Application Serial No.)	(Filing Date)	(Status-patented, pending, abo	andoned)	-
(Application Serial No.)	(Filing Date)	(Status-patented, pending, ab-	andoned)	_
(Application contaction)	(1 1111/6 24114)	(,	
Cooper, Reg. No. 27,625, Linda S.	. Chan, Reg. No. 42,400	, Reg. No. 18,923, Samson Helfgott, Reg. No.), Jacqueline M. Steady, Reg. No. 44,354 and it all business in the Patent and Trademark Off	d Harris	Wolin,
Address all correspondence to:		HELFGOTT & KARAS, P.C.		
		Empire State Building, 60th Floor		
		New York, New York 10118-0110		
		Telephone No.: (212) 643-5000		
and belief are believed to be true; a	nd further that these state	knowledge are true and that all statements made ements were made with the knowledge that wil	lful false	:
statements and the like so made are States Code and that such willful fa	punishable by fine or in lse statements may jeopa	nprisonment, or both, under Section 1001 of Ti ardize the validity of the application or any pat	tle 18 of ent issue	the Untied d thereon.
Full name of sole or first inventor_		承	· 	
Inventor's Signature <u>Phami</u>	miyaxaka (Date August 2, 2000		
Residence Tokyo, Japan	Corporation 7-1	Citizenship <u>Japanese</u> Shiba 5-chome, Minato-ku,		
Post Office Address <u>c/o NEC O</u> Tokyo, Ja		onina o-chome, minaco-ku,		
IONYO, U				
Full name of second joint inventor,				
Second Inventor's Signature		Date		
Residence		Citizenship		